ERRATUM

Erratum to: The properties of samarium-doped zinc oxide/phthalocyanine structure for optoelectronics prepared by pulsed laser deposition and organic molecular evaporation

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The original version of this article unfortunately contained a mistake.

The presentation of Fig. 6 was incorrect. The correct Fig. 6 is given below.

Fig. 6 XRD pattern of ZnO:Sm film deposited on silicon substrate

The online version of the original article can be found under doi:[10.1007/s00339-016-9759-6](https://doi.org/10.1007/s00339-016-9759-6).

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